Photointerrupter, Ultraminiature SMD type

Absolute maximum ratings (Ta=25°C)

	Parameter	Symbol	Limits	Unit
Input (LED)	Forward current	lF	30	mA
	Reverse voltage	VR	5	V
	Power dissipation	P□	80	mW
Output (photo- (transistor)	Collector-emitter voltage	Vceo	30	V
	Emitter-collector voltage	Veco	4.5	V
	Collector current	lc	30	mA
	Collector power dissipation	Pc	80	mW
	Operating temperature	Topr	-25 to +85	°C
	Storage temperature	Tstg	-30 to +85	°C

Applications

DSC(Digital steal camera) DVC(Digital video camera) Digital handy phone

Features

Ultraminiature SMD type.
 Gap 1.2mm.

Electrical and optical characteristics (Ta=25°C)

Parameter			Symbol	Min.	Тур.	Max.	Unit	Conditions
Input charac- teristics	Forward voltage		VF	1.2	1.35	1.5	V	I _F =5mA
	Reverse current		IR	-	-	10	μΑ	V _R =5V
Output charac- teristics	Dark current		ICEO	-	-	0.1	μΑ	Vce=10V
Out _p chai teris	Peak sensitivity wavelength		λР	-	800	-	nm	-
Transfer characteristics	Collector current		Ic1	5.0	-	25	mA	Vce=5V, Ir=20mA
			Ic2	1.0	-	5	mA	Vce=5V, Ir=5mA
	Collector-emitter saturation voltage		VCE(sat)	-	-	0.4	V	I _F =20mA, I _C =0.1mA
	Response time	Rise time	tr	-	10	-	μs	V 5V I 00A B 4000
		Fall time	tf	-	10	-	μs	Vcc=5V, I _F =20mA, R _L =100Ω
Infrared light emitter diode	Cut-off frequency		fc	-	1	-	MHz	Ir=5mA * Non-coherent Infrared light emitting diode used.
	Peak light emitting wavelength		λρ	-	850	-	nm	
Photo transistor	Response time		tr∙tf	-	10	_	μs	$\label{eq:CC_SV_IC} \begin{array}{l} V_{\text{CC}} = 5 V, \ I_{\text{C}} = 1 m A, \ R_{\text{L}} = 100 \Omega \\ * \ This product is not designed to be protected against electromagnetic wave. \end{array}$
	Maximum sensitivity wavelength		λρ	_	800	_	nm	-

Electrical and optical characteristics curves

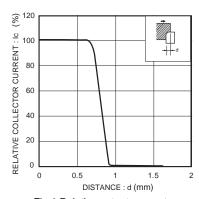


Fig.1 Relative output current vs. distance (I)

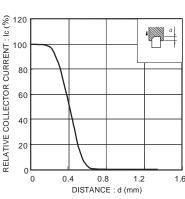


Fig.4 Relative output current vs. distance (II)

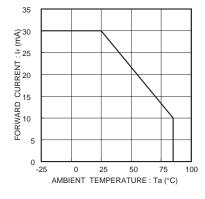


Fig.2 Forward current falloff

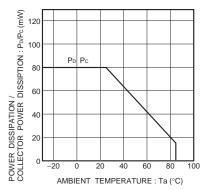


Fig.5 Power dissipation / collector power dissipation vs. ambient temperature

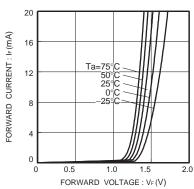


Fig.3 Forward current vs. forward voltage

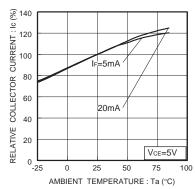
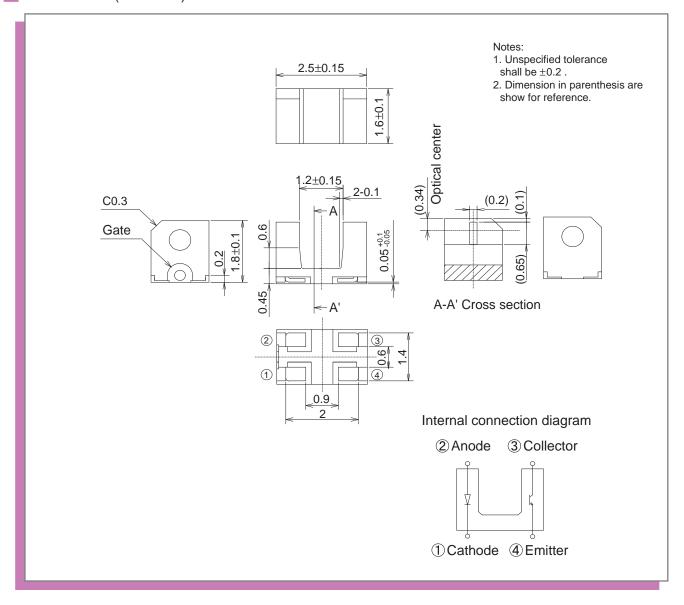
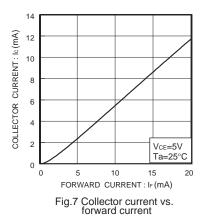


Fig.6 Relative output vs. ambient temperature





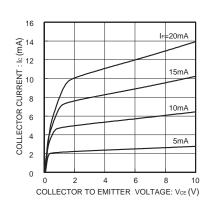


Fig.10 Output characteristics

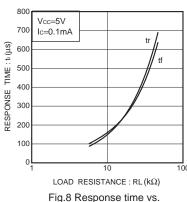
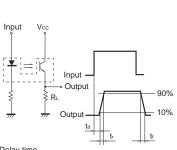


Fig.8 Response time vs. load resistance



- td: Delay time
- tr: Rise time (time for output current to rise from 10% to 90% of peak current)
- tr :Fall time (time for output current to fall from 90% to 10% of peak current)

1000 DARK CURRENT: ICEO (nA) Vce=30V VcE=20V 0.1 AMBIENT TEMPERATURE : Ta (°C)

Fig.9 Dark current vs. ambient temperature

Notes

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